NSN 5961-01-365-3742

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-365-3742 **Inclosure Material:** Glass or ceramic **Overall Length:** Between 0.120 inches and 0.200 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.055 inches and 0.090 inches **Function For Which Designed:** Voltage regulator **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 13.0 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0**Current Rating Per Characteristic:** 29.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification

81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 uninsulated wire lead

Specification Data:

81349-mil-prf-19500/437 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.